

Ultra Low Dropout Positive Fixed Linear Regulator

IRUH33P183A1M +3.3Vin to 1.8Vout at 3.0A

Product Summary

Part Number	Dropout	lo	v _{in}	v _{out}
IRUH33P183A1M	1.1V	3.0A	3.3V	1.8V



The IRUH33P183A1M is a space qualified, ultra low dropout linear regulator designed specifically for space applications. This product has been characterized to a total ionizing dose of 1.0 Mrad(Si) per MIL-STD-883, Method 1019 at both high and low dose rates under biased and unbiased conditions to account for ELDRS effects in bipolar devices. The ultra low dropout voltage of 1.1V @ 3A makes the part particularly useful for applications requiring low noise and higher efficiency.

Features:

- Total dose to 1.0 Mrad(Si) and low dose capability to 500 Krad(Si) allows use in space applications
- Single Event latchup Immune LET = 84 MeV/(mg/cm²) Fluency = 1 x 109 lons/cm²
- Low noise, higher efficiency
- Ultra low dropout voltage of 1.1V@ 3A out significantly reduces power consumption
- Remote shutdown permits power sequencing to be easily implemented
- Hermetic 8-Lead Flat Pack ensures higher reliability
- Space Level Screened
- This part is also available in MO-078 Package as IRUH33P183B1M

Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Output Current	Io	3.5	Α
Input Voltage	V _{IN}	7.0	V
Power Dissipation, T _C = 25°C	P _{TOT}	19	W
Thermal Resistance, Junction to Case	R _{THJC}	6.5	°C/W
Operating Temperature Range	T _J	-55 to +125	
Storage Temperature Range	T _S	-65 to +150	°C
Lead Temperature	TL	300	

Pre-Radiation

Electrical Characteristics @T_C = 25°C (Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	$V_{IN} = 3.3V, I_{O} = 1.5A$		1.782	1.8	1.818	
	V _{IN} = 2.97V, I _O = 50mA		1.71	-	1.89	,
Output Voltage	$V_{IN} = 2.97V, I_{O} = 3.0A$	V _{OUT}	1.71	-	1.89	
	V _{IN} = 3.63V, I _O = 50mA		1.71	-	1.89	V
	$V_{IN} = 3.63V, I_{O} = 3.0A$		1.71	-	1.89	,
Input Voltage Range - Operating	I _O = 3.0A	V _{IN}	2.9	-	6.5	,
Dropout Voltage	$I_{O} = 3.0A, V_{OUT} = 2.5V$	V_{DROP}	-	-	1.1	
Current Limit	V _{IN} = 5.0V, Overcurrent Latchup	I _{LATCH}	3.0	-	-	Α
Ripple Rejection	F = 120Hz, I _O = 50mA		65	-	-	dB
Shutdown Source Current	V _{SHDN} = 5.0V	I _{SHDN}	-	200	-	μΑ
Shutdown Pin Threshold ①	$V_{IN} = 5.0V$	V _{SHDN}	1.0	ı	1.6	· V
Output Voltage at Shutdown	$V_{IN} = 3.3V$, $I_{O} = 50$ mA, $V_{SHDN} = +5.0V$	V _{OUT (SHDN)}	-0.1		+0.1	٧

Pre-Radiation

Electrical Characteristics @T_C = -55°C to 125°C (Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	$V_{IN} = 3.3V, I_{O} = 1.5A$		1.71	1.8	1.89	
	$V_{IN} = 2.97V, I_O = 50mA$		1.71	-	1.89	V
Output Voltage	$V_{IN} = 2.97V, I_O = 3.0A$	V_{OUT}	1.71	-	1.89	
	$V_{IN} = 3.63V, I_{O} = 50mA$		1.71	-	1.89	
	$V_{IN} = 3.63V, I_{O} = 3.0A$		1.71	1	1.89	
Input Voltage Range - Operating	$I_{O} = 3.0A$	V_{IN}	2.9	-	6.5	
Dropout Voltage	$I_O = 3.0A, V_{OUT} = 2.5V$	V_{DROP}	-	-	1.1	
Current Limit	V _{IN} = 5.0V, Overcurrent Latchup	I _{LATCH}	3.0	-	-	Α
Ripple Rejection	F = 120Hz, I _O = 50mA		65	-	-	dB
Shutdown Source Current	V _{SHDN} = 5.0V	I _{SHDN}	-	200	-	μΑ
Shutdown Pin Threshold ①	$V_{IN} = 5.0V$	V _{SHDN}	1.0	1	1.6	
Output Voltage at Shutdown	$V_{IN} = 3.3V$, $I_O = 50$ mA, $V_{SHDN} = +5.0V$	V _{OUT} (SHDN)	-0.1	-	+0.1	V

For notes, please refer to page 3



Post-Radiation

Electrical Characteristics @T_C = 25°C (Unless Otherwise Specified)

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
	V _{IN} = 3.3V, I _O = 1.5A		1.71	1.8	1.89	
	$V_{IN} = 2.97V, I_O = 50mA$		1.71	-	1.89	
Output Voltage	$V_{IN} = 2.97V, I_O = 3.0A$	V _{OUT}	1.71	-	1.89	V
	V _{IN} = 3.63V, I _O = 50mA		1.71	-	1.89	
	V _{IN} = 3.63V, I _O = 3.0A		1.71	-	1.89	
Current Limit	V _{IN} = 3.3V	I _{MAX}	3.0	-	-	Α
Ripple Rejection	F = 120Hz, I _O = 50mA		40	-	-	dB
Output Voltage at Shutdown	$V_{IN} = 5.0V, I_{O} = 50mA, V_{SHDN} = +5.0V$	V _{OUT (SHDN)}	-0.1	-	+0.1	V

Notes for Electrical Characteristic Tables

 $[\]circ$ V $_{\mathrm{Shutdown}}$ ramp from 0.8V to 4.8V, output monitored for a 100mV drop below the nominal specification for V $_{\mathrm{out}}$

Pre-Radiation Characteristics

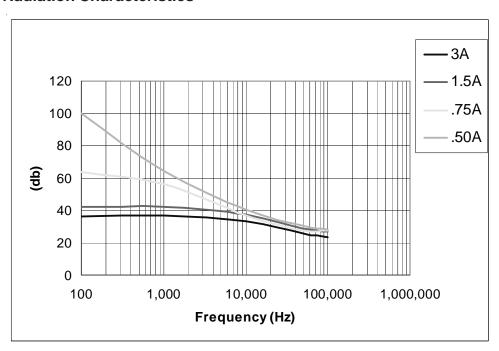


Fig 1. Ripple Rejection Vs Frequency

Radiation Performance Characteristics

Test	Conditions	Min	Тур	Unit
	MIL-STD-883, Method 1019			
Total Ionizing Dose (Gamma)	Operating Bias applied during exposure	1,000		Krads (Si)
	Full Rated Load, Vin=3.3V			
Neutron Fluence	MIL-STD-883, Method 1017	1.00E+09	1.00E+13	Neutrons/cm ²
Single Event effects	Heavy Ions (LET)			
SEU, SEL, SEGR, SEB	Operating Bias applied during exposure	84		MeV*cm ² /mg
	Full Rated Load, Vin=3.3 V			

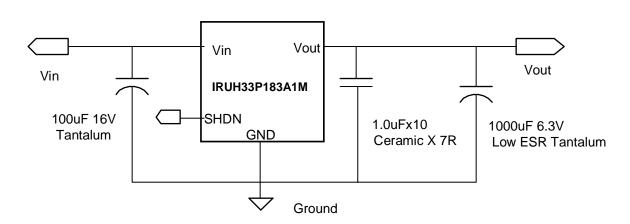


Fig 2. Typical Application Circuit

Input Capacitance

Recommended input capacitance for a generic application is a $100\mu F$, 16V tantalum capacitor. However, the input capacitance is not critical to the stability of the regulator and is therefore application dependant. In designs with a clean bus voltage that is situated close to the input of the regulator, only a small ceramic capacitor will be needed to decouple high frequency noise. On the other hand, in designs with a noisy bus, a larger capacitor will be needed. Care should be taken to ensure that the input to the regulator is sufficiently free of noise and disturbances.

Output Capacitance

Like most ultra low dropout voltage regulators, IRUH33P183A1M requires the use of output capacitors as part of the device frequency compensation. The device requires a minimum of $220\mu F$ tantalum to ensure stability.

Many different types of capacitor are available and have widely varying characteristics. These capacitors differ in capacitor tolerance, equivalent series resistance (ESR), equivalent series inductance and capacitance temperature coefficient. The IRUH33P183A1M frequency compensation optimizes frequency response with low ESR capacitors. In general, use capacitors with an ESR of less than $50m\Omega$ for heavy load applications.

High quality bypass capacitors must be also be used to limit the high frequency noise generated by the load. Multiple small ceramic capacitors are typically required to limit parasitic inductance (ESL) and ESR in the capacitors to acceptable levels.

The upper limit of the capacitance is governed by the delayed over-current latch function of the regulator. The regulator has a protection circuit that will latch the device off in the event of a short circuit. However, since it is known that the regulator will draw a large in-rush current upon startup, the latch-off is delayed by about 10ms to allow the outout capacitors to charge to a steady state without shutting down. During this period, the regulator will have an output current at its maximum of around 5A typical. Therefore, the maximum output capacitance can be as high as $20,000\mu F$ without causing device to latch-off during start-up.

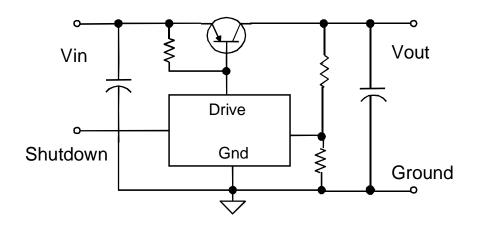


Fig 3. Simplified Schematic Circuit

Space Level Screening Requirements

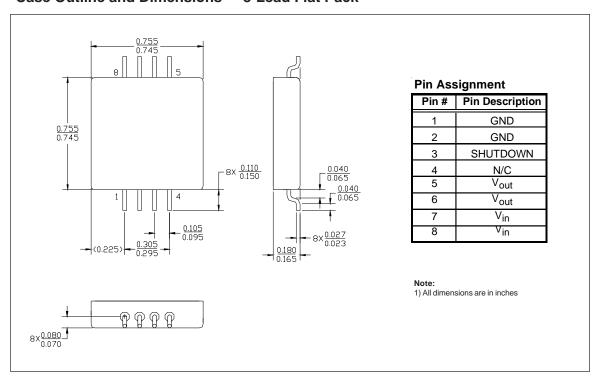
TEST/INSPECTION	SCREENING LEVEL	MIL-STD-883	
	SPACE	METHOD	
Pre Seal Burn-In	Optional	1030	
Nondestructive Bond Pull	100%	2023	
Internal Visual	100%	2017	
Temperature Cycle	100%	1010	
Constant Acceleration	100%	2001	
Mechanical Shock	100%	2002	
PIND	100%	2020	
Pre Burn-In-Electrical	100%		
Burn-In	100%	1015	
Final Electrical	100%		
Seal	100%	1014	
Radiographic	100%	2012	
External Visual	100%	2009	

Note:

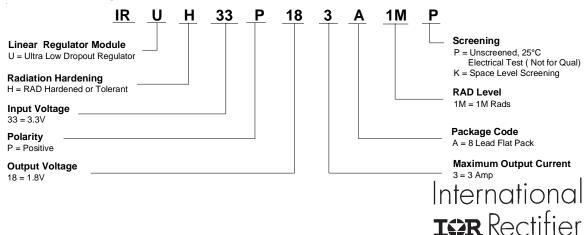
International Rectifier doesnot currently have a DSCC certified Radiation Hardness Assurance Program



Case Outline and Dimensions - 8-Lead Flat Pack



Part Numbering Nomenclature



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Data and specifications subject to change without notice. 11/2005